

# 70V3579S4DR

#### 70V3579S4DR Information

www.heisener.com	Part Number Manufacturer Category Description Package	70V3579S4DR IDT, Integrated Device Technology Inc Integrated Circuits (ICs) Memory IC SRAM 1.125MBIT 4.2NS 208QFP 208-BFQFP For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



### 70V3579S4DR Specifications

Manufacturer Part Number	70V3579S4DR
Manufacturer	IDT, Integrated Device Technology Inc
Category	Integrated Circuits (ICs)
	Memory
Package	208-BFQFP
Series	-
Memory Type	Volatile
Memory Format	SRAM
Technology	SRAM - Dual Port, Synchronous
Memory Size	1.125Mb (32K x 36)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	-
Access Time	4.2ns
Voltage - Supply	3.15 V ~ 3.45 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
	Report errors?

#### 70V3579S4DR Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE UARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### 70V3579S4DR Payment Methods





If you have any question about 70V3579S4DR, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com